1PS76SB10

Schottky barrier single diode

17 December 2012

Product data sheet

1. General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a very small SOD323 Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

3. Applications

- Ultra high-speed switching
- Line termination
- Voltage clamping
- Reverse polarity protection

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		-	-	200	mA
V _R	reverse voltage		-	-	30	V
V _F	forward voltage	I_F = 10 mA; pulsed; t_p = 300 μs; δ = 0.02 ; T_{amb} = 25 °C	-	-	400	mV

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	1 2	к - Д-а
2	Α	anode	SOD323	aaa-003679

[1] The marking bar indicates the cathode.





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6. Ordering information

Table 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
1PS76SB10	SOD323	plastic surface-mounted package; 2 leads	SOD323				

7. Marking

Table 4. Marking codes

Type number	Marking code
1PS76SB10	S0

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	30	V
l _F	forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	-	300	mA
I _{FSM}	non-repetitive peak forward current	t_p < 10 ms; $T_{j(init)}$ = 25 °C	-	600	mA
T _j	junction temperature		-	125	°C
T _{amb}	ambient temperature		-55	125	°C
T _{stg}	storage temperature		-65	150	°C

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	450	K/W

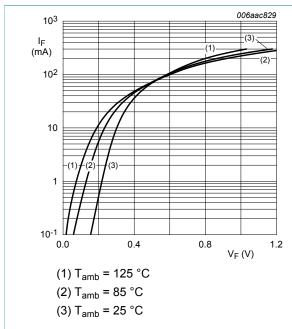
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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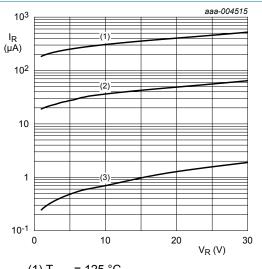
10. Characteristics

Table 7. **Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F forward voltage	forward voltage	I_F = 0.1 mA; pulsed; t_p = 300 μs; δ = 0.02 ; T_{amb} = 25 °C	-	-	240	mV
		I_F = 1 mA; pulsed; t_p = 300 μs; δ = 0.02 ; T_{amb} = 25 °C	-	-	320	mV
		I_F = 10 mA; pulsed; t_p = 300 μs; δ = 0.02 ; T_{amb} = 25 °C	-	-	400	mV
		I_F = 30 mA; pulsed; t_p = 300 µs; δ = 0.02 ; T_{amb} = 25 °C	-	-	500	mV
		I_F = 100 mA; pulsed; t_p = 300 μs; δ = 0.02 ; T_{amb} = 25 °C	-	-	800	mV
I _R	reverse current	V_R = 25 V; pulsed; t_p = 300 µs; δ = 0.02 ; T_{amb} = 25 °C	-	-	2	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _{amb} = 25 °C	-	-	10	pF



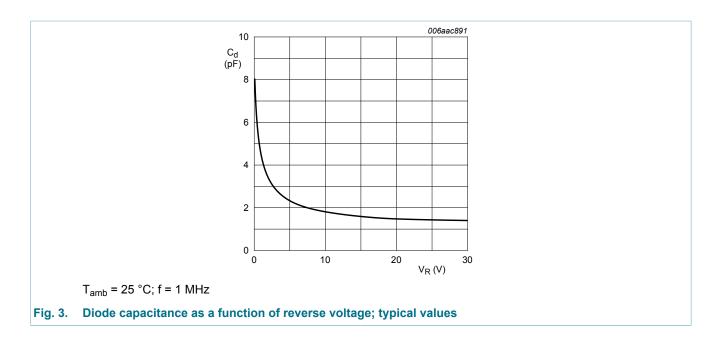
Forward current as a function of forward Fig. 1. voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) T_{amb} = 85 °C
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig. 2. Reverse current as a function of reverse voltage; typical values

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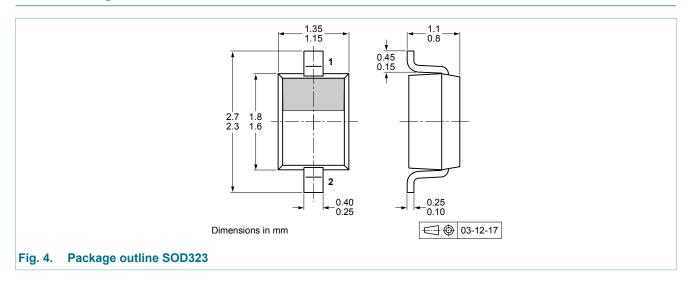


11. Test information

11.1 Quality information

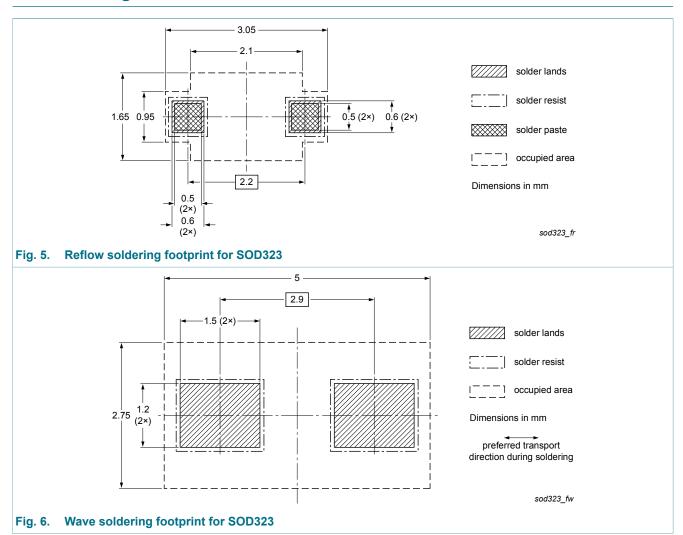
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
1PS76SB10 v.4	20121217	Product data sheet	-	1PS76SB10 v.3
Modifications:	Section "ApplicTable 5 "Limitir	res and benefits" updated cations" updated ng values": ambient temperateteristics": forward voltage \nd 3 updated		lue updated
1PS76SB10 v.3	20120718	Product data sheet	-	1PS76SB10 v.2
1PS76SB10 v.2	20040126	Product specification	-	1PS76SB10 v.1
1PS76SB10 v.1	19961014	Product specification	-	-

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15. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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